

LMV1012 Analog Series: Pre-Amplified IC's for High Gain 2-Wire Microphones

Check for Samples: [LMV1012](#)

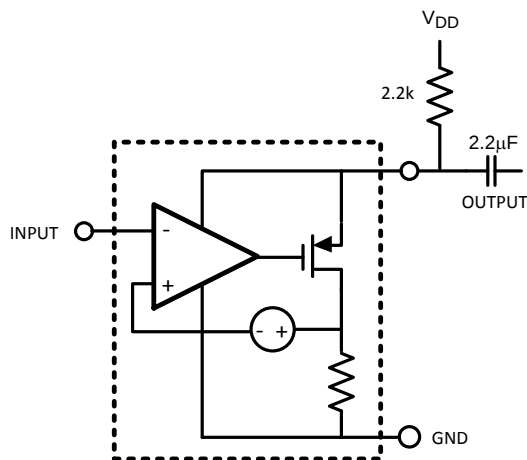
FEATURES

- Typical LMV1012-15, 2.2V Supply, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, $V_{IN} = 18\text{ mV}_{PP}$, Unless Otherwise Specified
- Supply Voltage: 2V - 5V
- Supply Current: <180 μA
- Signal to Noise Ratio (A-Weighted): 60 dB
- Output Voltage Noise (A-Weighted): -89 dBV
- Total Harmonic Distortion: 0.09%
- Voltage Gain
 - LMV1012-07: 7.8 dB
 - LMV1012-15: 15.6 dB
 - LMV1012-20: 20.9 dB
 - LMV1012-25: 23.8 dB
- Temperature Range: -40°C to 85°C
- Offered in 4-Bump DSBGA Packages

APPLICATIONS

- Cellular Phones
- Headsets
- Mobile Communications
- Automotive Accessories
- PDAs
- Accessory Microphone Products

Schematic Diagram



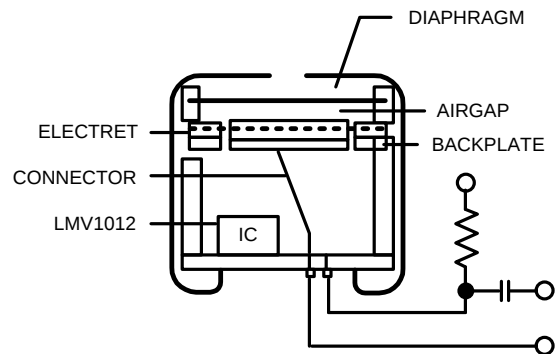
DESCRIPTION

The LMV1012 is an audio amplifier series for small form factor electret microphones. This 2-wire portfolio is designed to replace the JFET amplifier currently being used. The LMV1012 series is ideally suited for applications requiring high signal integrity in the presence of ambient or RF noise, such as in cellular communications. The LMV1012 audio amplifiers are specified to operate over a 2.2V to 5.0V supply voltage range with fixed gains of 7.8 dB, 15.6 dB, 20.9 dB, and 23.8 dB. The devices offer excellent THD, gain accuracy and temperature stability as compared to a JFET microphone.

The LMV1012 series enables a two-pin electret microphone solution, which provides direct pin-to-pin compatibility with the existing JFET market.

The devices are offered in extremely thin space saving 4-bump DSBGA packages. The LMV1012XP is designed for 1.0 mm canisters and thicker ECM canisters. These extremely miniature packages are designed for electret condenser microphones (ECM) form factor.

Built-In Gain Electret Microphone



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

Absolute Maximum Ratings⁽¹⁾⁽²⁾

ESD Tolerance ⁽³⁾	Human Body Model	2500V
	Machine Model	250V
Supply Voltage	V _{DD} - GND	5.5V
Storage Temperature Range		-65°C to 150°C
Junction Temperature ⁽⁴⁾		150°C max
Mounting Temperature	Infrared or Convection (20 sec.)	235°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the [5V Electrical Characteristics](#).
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) Human Body Model (HBM) is 1.5 kΩ in series with 100 pF.
- (4) The maximum power dissipation is a function of T_{J(MAX)}, θ_{JA} and T_A. The maximum allowable power dissipation at any ambient temperature is P_D = (T_{J(MAX)} - T_A)/θ_{JA}. All numbers apply for packages soldered directly into a PC board.

Operating Ratings⁽¹⁾

Supply Voltage	2V to 5V
Temperature Range	-40°C to 85°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the [5V Electrical Characteristics](#).

2.2V Electrical Characteristics⁽¹⁾

Unless otherwise specified, all limits are specified for $T_J = 25^\circ\text{C}$, $V_{DD} = 2.2\text{V}$, $V_{IN} = 18\text{ mV}$, $R_L = 2.2\text{ k}\Omega$ and $C = 2.2\text{ }\mu\text{F}$.

Boldface limits apply at the temperature extremes.

Symbol	Parameter	Conditions		Min ⁽²⁾	Typ ⁽³⁾	Max ⁽²⁾	Units
I_{DD}	Supply Current	$V_{IN} = \text{GND}$	LMV1012-07		139	250 300	μA
			LMV1012-15		180	300 325	
			LMV1012-20		160	250 300	
			LMV1012-25		141	250 300	
SNR	Signal to Noise Ratio	$f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}$, A-Weighted	LMV1012-07		59		dB
			LMV1012-15		60		
			LMV1012-20		61		
			LMV1012-25		61		
V_{IN}	Max Input Signal	$f = 1\text{ kHz}$ and THD+N < 1%	LMV1012-07		170		mV_{PP}
			LMV1012-15		100		
			LMV1012-20		50		
			LMV1012-25		28		
V_{OUT}	Output Voltage	$V_{IN} = \text{GND}$	LMV1012-07	1.65 1.54	1.90	2.03 2.09	V
			LMV1012-15	1.54 1.48	1.81	1.94 2.00	
			LMV1012-20	1.65 1.55	1.85	2.03 2.13	
			LMV1012-25	1.65 1.49	1.90	2.02 2.18	
f_{LOW}	Lower –3dB Roll Off Frequency	$R_{SOURCE} = 50\Omega$			65		Hz
f_{HIGH}	Upper –3dB Roll Off Frequency	$R_{SOURCE} = 50\Omega$			95		kHz
e_n	Output Noise	A-Weighted	LMV1012-07		–96		dBV
			LMV1012-15		–89		
			LMV1012-20		–84		
			LMV1012-25		–82		
THD	Total Harmonic Distortion	$f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}$	LMV1012-07		0.10		%
			LMV1012-15		0.09		
			LMV1012-20		0.12		
			LMV1012-25		0.15		
C_{IN}	Input Capacitance				2		pF
Z_{IN}	Input Impedance				>1000		G Ω
A_V	Gain	$f = 1\text{ kHz}$, $R_{SOURCE} = 50\Omega$	LMV1012-07	6.4 5.5	7.8	9.5 10.0	dB
			LMV1012-15	14.0 13.1	15.6	16.9 17.5	
			LMV1012-20	19.5 17.4	20.9	22.0 23.3	
			LMV1012-25	22.5 21.4	23.8	25.0 25.7	

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.
- (2) All limits are specified by design or statistical analysis.
- (3) Typical values represent the most likely parametric norm.

5V Electrical Characteristics⁽¹⁾

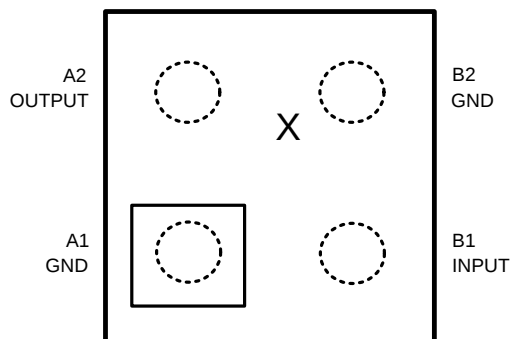
Unless otherwise specified, all limits are specified for $T_J = 25^\circ\text{C}$, $V_{DD} = 5\text{V}$, $V_{IN} = 18\text{ mV}$, $R_L = 2.2\text{ k}\Omega$ and $C = 2.2\text{ }\mu\text{F}$.

Boldface limits apply at the temperature extremes.

Symbol	Parameter	Conditions		Min ⁽²⁾	Typ ⁽³⁾	Max ⁽²⁾	Units
I_{DD}	Supply Current	$V_{IN} = \text{GND}$	LMV1012-07		158	250 300	μA
			LMV1012-15		200	300 325	
			LMV1012-20		188	260 310	
			LMV1012-25		160	250 300	
SNR	Signal to Noise Ratio	$f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}$, A-Weighted	LMV1012-07		59		dB
			LMV1012-15		60		
			LMV1012-20		61		
			LMV1012-25		61		
V_{IN}	Max Input Signal	$f = 1\text{ kHz}$ and $\text{THD+N} < 1\%$	LMV1012-07		170		mV_{PP}
			LMV1012-15		100		
			LMV1012-20		55		
			LMV1012-25		28		
V_{OUT}	Output Voltage	$V_{IN} = \text{GND}$	LMV1012-07	4.45 4.38	4.65	4.80 4.85	V
			LMV1012-15	4.34 4.28	4.56	4.74 4.80	
			LMV1012-20	4.40 4.30	4.58	4.75 4.85	
			LMV1012-25	4.45 4.39	4.65	4.83 4.86	
f_{LOW}	Lower -3dB Roll Off Frequency	$R_{SOURCE} = 50\Omega$			67		Hz
f_{HIGH}	Upper -3dB Roll Off Frequency	$R_{SOURCE} = 50\Omega$			150		kHz
e_n	Output Noise	A-Weighted	LMV1012-07		-96		dBV
			LMV1012-15		-89		
			LMV1012-20		-84		
			LMV1012-25		-82		
THD	Total Harmonic Distortion	$f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}$	LMV1012-07		0.12		%
			LMV1012-15		0.13		
			LMV1012-20		0.18		
			LMV1012-25		0.21		
C_{IN}	Input Capacitance				2		pF
Z_{IN}	Input Impedance				>1000		G Ω
A_V	Gain	$f = 1\text{ kHz}$, $R_{SOURCE} = 50\Omega$	LMV1012-07	6.4 5.5	8.1	9.5 10.7	dB
			LMV1012-15	14.0 13.1	15.6	16.9 17.5	
			LMV1012-20	19.2 17.0	21.1	22.3 23.5	
			LMV1012-25	22.5 21.2	23.9	25.0 25.8	

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.
- (2) All limits are specified by design or statistical analysis.
- (3) Typical values represent the most likely parametric norm.

Connection Diagram



4-Bump DSBGA (Top View)

NOTE

Pin numbers are referenced to package marking text orientation.

The actual physical placement of the package marking will vary slightly from part to part. The package will designate the date code and will vary considerably. Package marking does not correlate to device type in any way.

Typical Performance Characteristics

Unless otherwise specified, $V_S = 2.2V$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$

Supply Current vs. Supply Voltage (LMV1012-07)

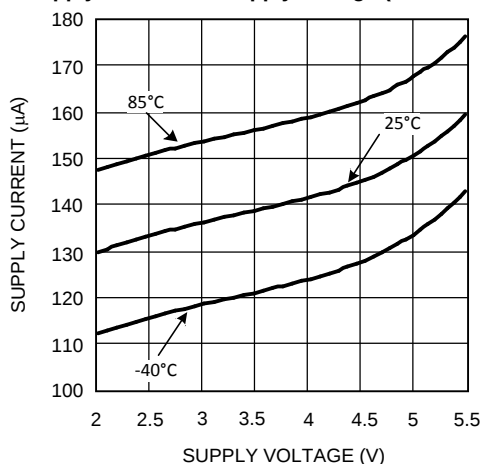


Figure 1.

Supply Current vs. Supply Voltage (LMV1012-15)

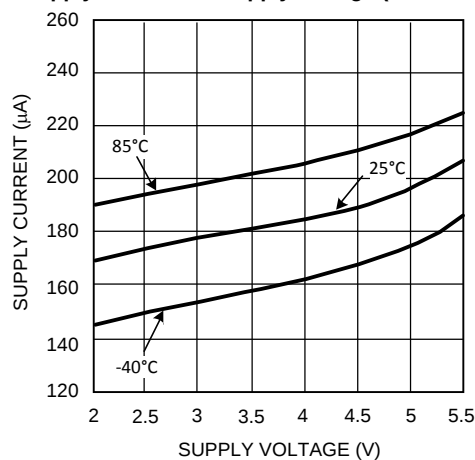


Figure 2.

Supply Current vs. Supply Voltage (LMV1012-20)

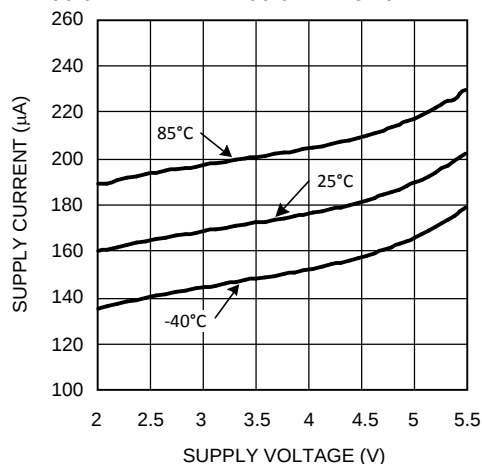


Figure 3.

Supply Current vs. Supply Voltage (LMV1012-25)

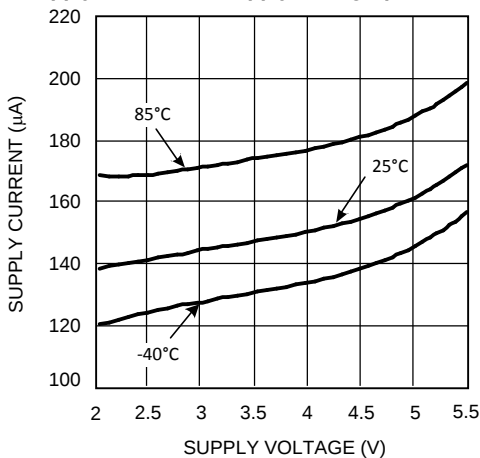


Figure 4.

Gain and Phase vs. Frequency (LMV1012-07)

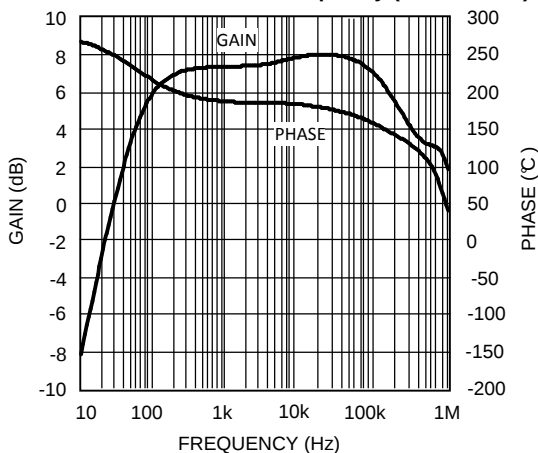


Figure 5.

Gain and Phase vs. Frequency (LMV1012-15)

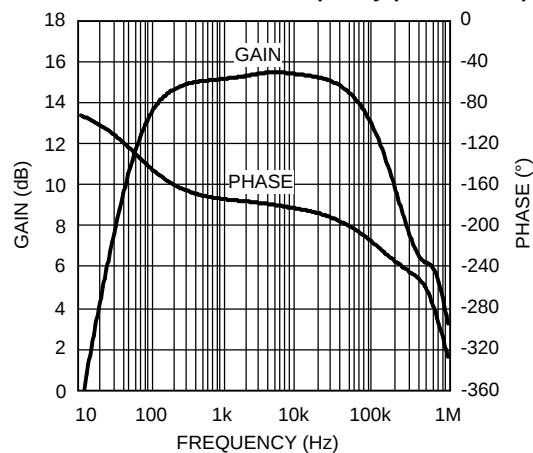


Figure 6.

Typical Performance Characteristics (continued)

Unless otherwise specified, $V_S = 2.2\text{V}$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$

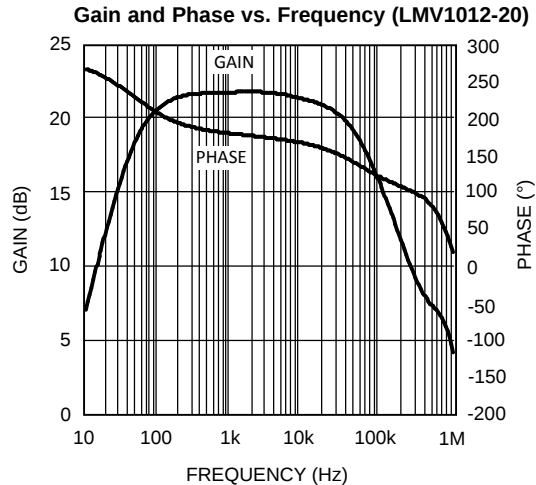


Figure 7.

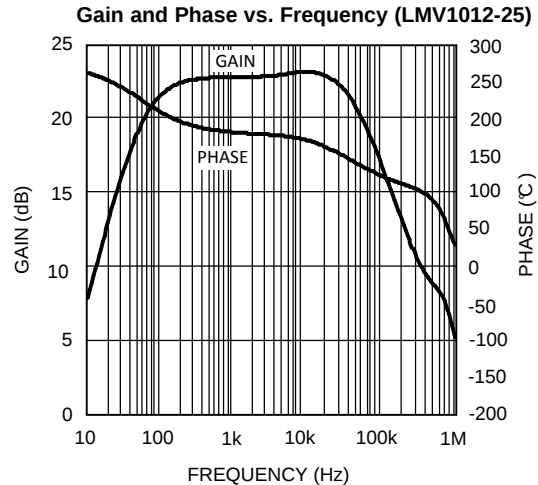


Figure 8.

Total Harmonic Distortion vs. Frequency (LMV1012-07)

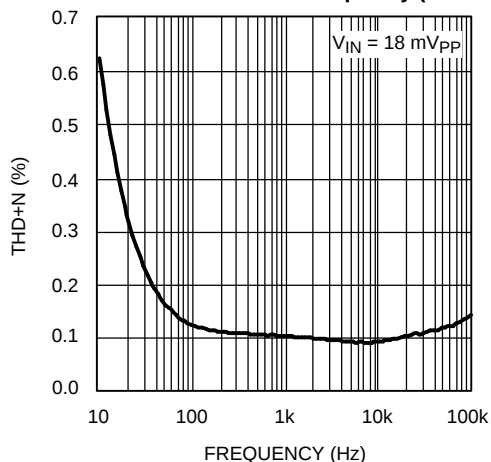


Figure 9.

Total Harmonic Distortion vs. Frequency (LMV1012-15)

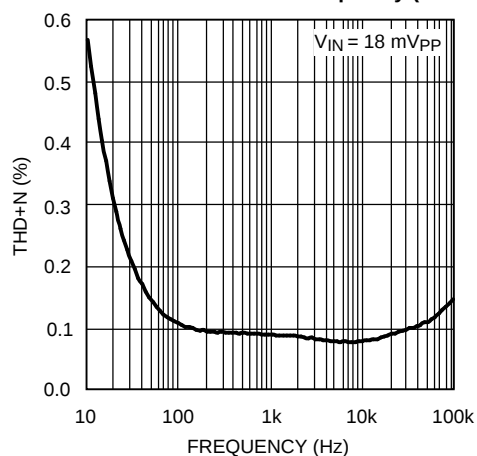


Figure 10.

Total Harmonic Distortion vs. Frequency (LMV1012-20)

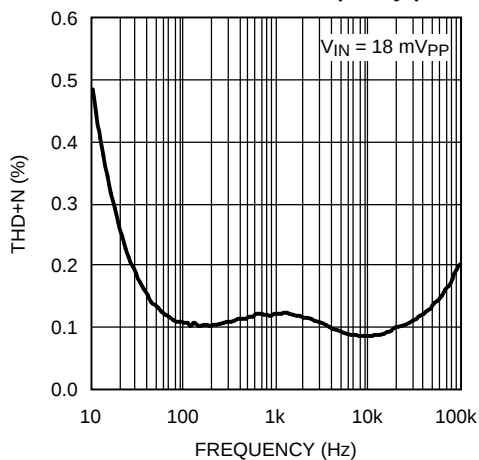


Figure 11.

Total Harmonic Distortion vs. Frequency (LMV1012-25)

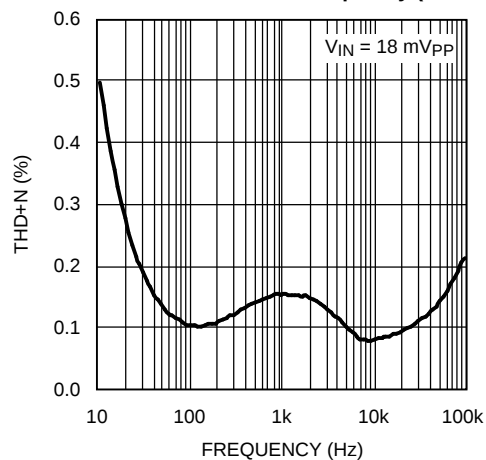


Figure 12.

Typical Performance Characteristics (continued)

Unless otherwise specified, $V_S = 2.2\text{V}$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$

Total Harmonic Distortion vs. Input Voltage (LMV1012-07)

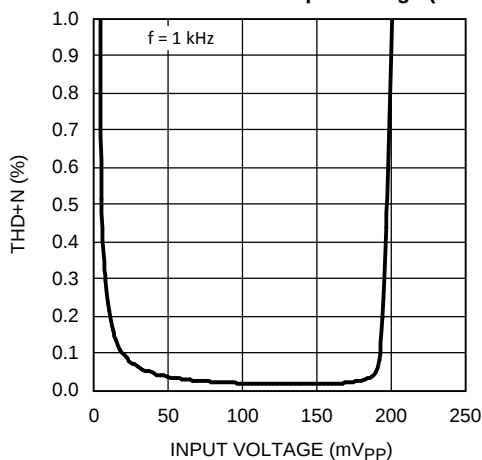


Figure 13.

Total Harmonic Distortion vs. Input Voltage (LMV1012-15)

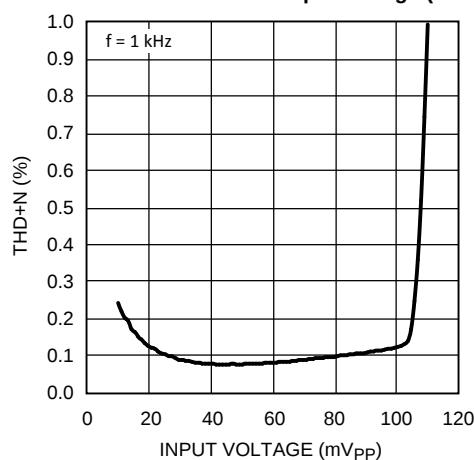


Figure 14.

Total Harmonic Distortion vs. Input Voltage (LMV1012-20)

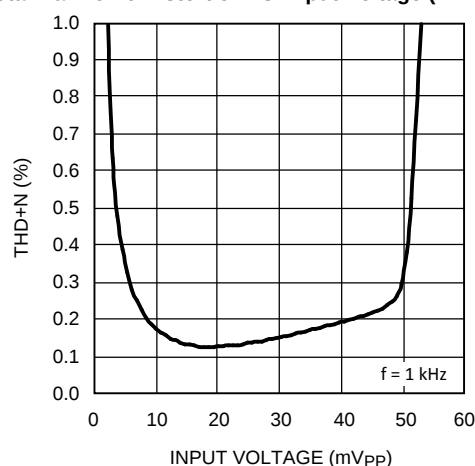


Figure 15.

Total Harmonic Distortion vs. Input Voltage (LMV1012-25)

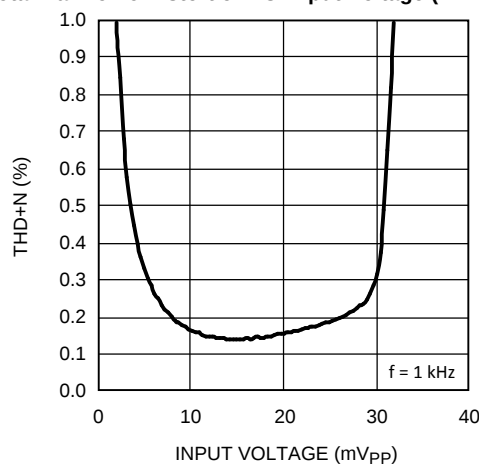


Figure 16.

Output Noise vs. Frequency (LMV1012-07)

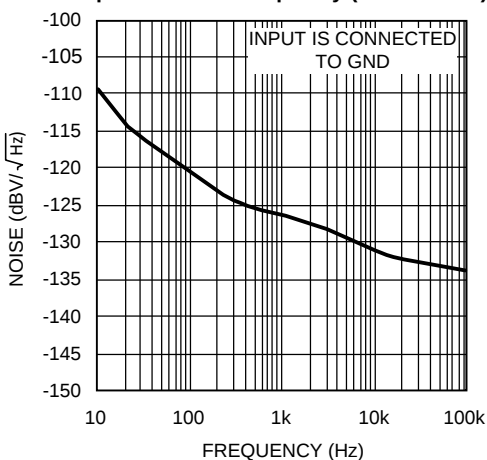


Figure 17.

Output Noise vs. Frequency (LMV1012-15)

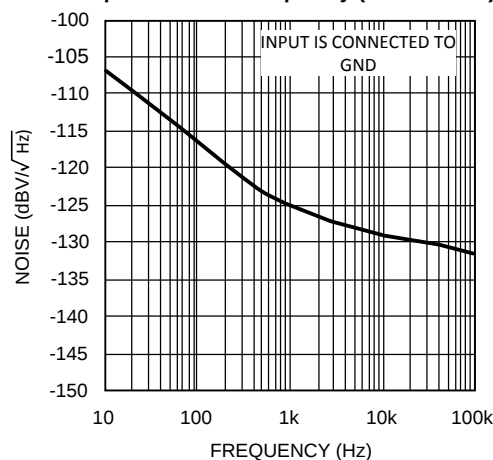


Figure 18.

Typical Performance Characteristics (continued)

Unless otherwise specified, $V_S = 2.2\text{V}$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$

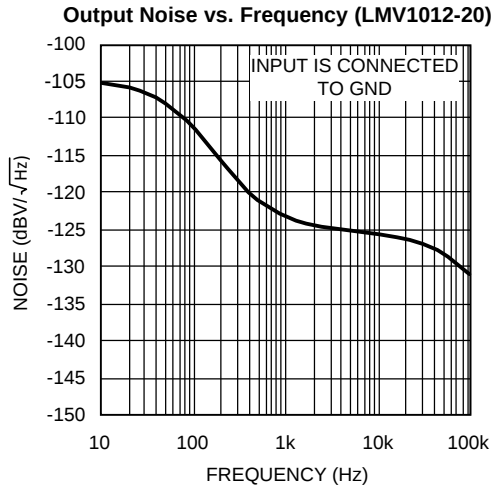


Figure 19.

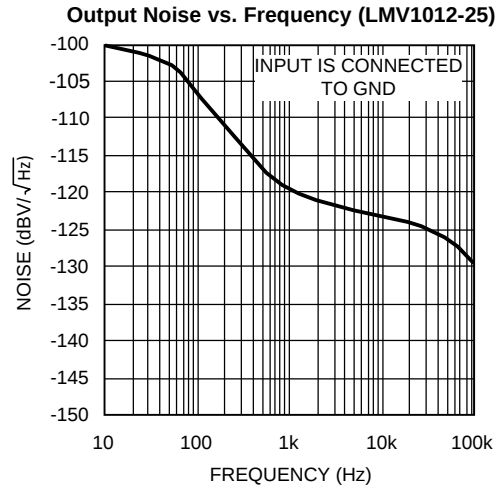


Figure 20.

APPLICATION SECTION

HIGH GAIN

The LMV1012 series provides outstanding gain versus the JFET and still maintains the same ease of implementation, with improved gain, linearity and temperature stability. A high gain eliminates the need for extra external components.

BUILT IN GAIN

The LMV1012 is offered in 0.3 mm height space saving small 4-pin DSBGA packages in order to fit inside the different size ECM canisters of a microphone. The LMV1012 is placed on the PCB inside the microphone.

The bottom side of the PCB usually shows a bull's eye pattern where the outer ring, which is shorted to the metal can, should be connected to the ground. The center dot on the PCB is connected to the V_{DD} through a resistor. This phantom biasing allows both supply voltage and output signal on one connection.

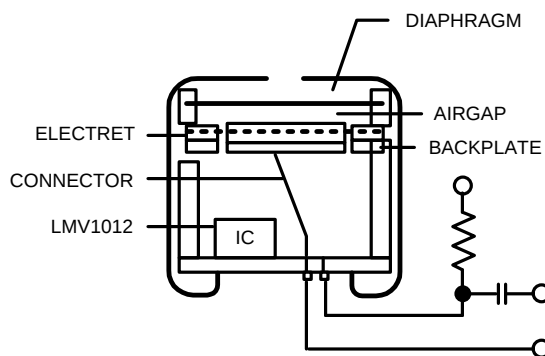


Figure 21. Built in Gain

A-WEIGHTED FILTER

The human ear has a frequency range from 20 Hz to about 20 kHz. Within this range the sensitivity of the human ear is not equal for each frequency. To approach the hearing response weighting filters are introduced. One of those filters is the A-weighted filter.

The A-weighted filter is usually used in signal to noise ratio measurements, where sound is compared to device noise. This filter improves the correlation of the measured data to the signal to noise ratio perceived by the human ear.

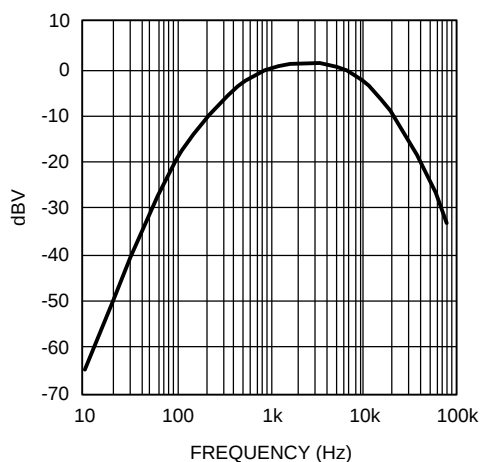


Figure 22. A-Weighted Filter

MEASURING NOISE AND SNR

The overall noise of the LMV1012 is measured within the frequency band from 10 Hz to 22 kHz using an A-weighted filter. The input of the LMV1012 is connected to ground with a 5 pF capacitor, as in Figure 23. Special precautions in the internal structure of the LMV1012 have been taken to reduce the noise on the output.

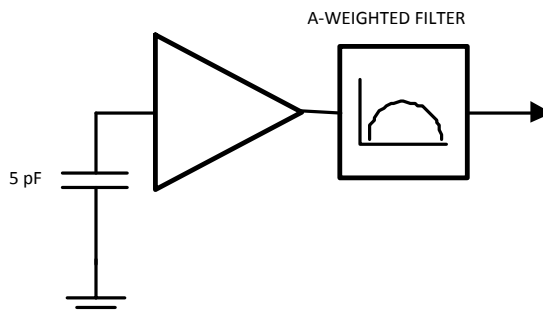


Figure 23. Noise Measurement Setup

The signal to noise ratio (SNR) is measured with a 1 kHz input signal of 18 mV_{pp} using an A-weighted filter. This represents a sound pressure level of 94 dB SPL. No input capacitor is connected for the measurement.

SOUND PRESSURE LEVEL

The volume of sound applied to a microphone is usually stated as a pressure level referred to the threshold of hearing of the human ear. The sound pressure level (SPL) in decibels is defined by:

$$\text{Sound pressure level (dB)} = 20 \log P_m/P_o$$

where

- P_m is the measured sound pressure
- P_o is the threshold of hearing (20 μ Pa).

(1)

In order to be able to calculate the resulting output voltage of the microphone for a given SPL, the sound pressure in dB SPL needs to be converted to the absolute sound pressure in dBPa. This is the sound pressure level in decibels referred to 1 Pascal (Pa).

The conversion is given by:

$$\text{dBPa} = \text{dB SPL} + 20 \log 20 \mu\text{Pa} \quad (2)$$

$$\text{dBPa} = \text{dB SPL} - 94 \text{ dB} \quad (3)$$

Translation from absolute sound pressure level to a voltage is specified by the sensitivity of the microphone. A conventional microphone has a sensitivity of -44 dBV/Pa.

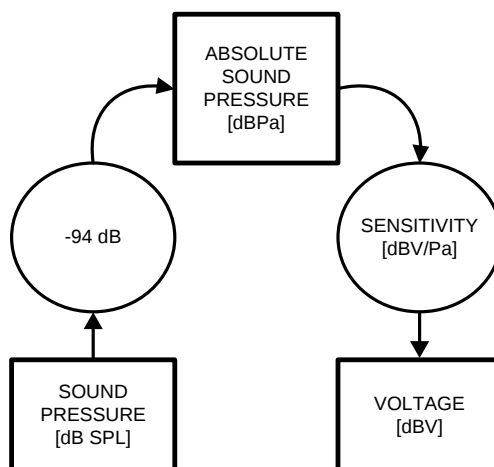


Figure 24. dB SPL to dBV Conversion

Example: Busy traffic is 70 dB SPL

$$V_{OUT} = 70 - 94 - 44 = -68 \text{ dBV}$$

(4)

This is equivalent to 1.13 mV_{PP}

Since the LMV1012-15 has a gain of 6 (15.6 dB) over the JFET, the output voltage of the microphone is 6.78 mV_{PP}. By implementing the LMV1012-15, the sensitivity of the microphone is -28.4 dBV/Pa (-44 + 15.6).

LOW FREQUENCY CUT OFF FILTER

To reduce noise on the output of the microphone a low frequency cut off filter has been implemented. This filter reduces the effect of wind and handling noise.

It's also helpful to reduce the proximity effect in directional microphones. This effect occurs when the sound source is very close to the microphone. The lower frequencies are amplified which gives a bass sound. This amplification can cause an overload, which results in a distortion of the signal.

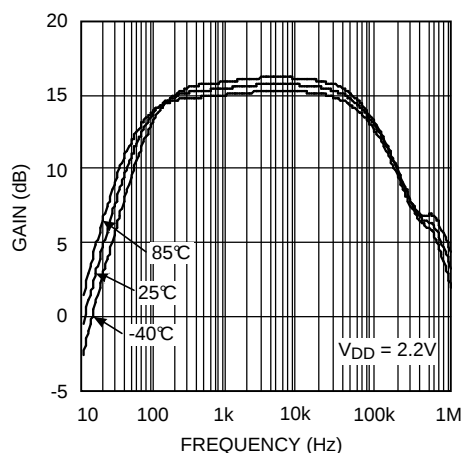


Figure 25. LMV1012-15 Gain vs. Frequency Over Temperature

The LMV1012 is optimized to be used in audio band applications. By using the LMV1012, the gain response is flat within the audio band and has linearity and temperature stability (see [Figure 25](#)).

NOISE

Noise pick-up by a microphone in cell phones is a well-known problem. A conventional JFET circuit is sensitive for noise pick-up because of its high output impedance, which is usually around 2.2 k Ω .

RF noise is amongst other caused by non-linear behavior. The non-linear behavior of the amplifier at high frequencies, well above the usable bandwidth of the device, causes AM-demodulation of high frequency signals. The AM modulation contained in such signals folds back into the audio band, thereby disturbing the intended microphone signal. The GSM signal of a cell phone is such an AM-modulated signal. The modulation frequency of 216 Hz and its harmonics can be observed in the audio band. This kind of noise is called bumblebee noise.

RF noise caused by a GSM signal can be reduced by connecting two external capacitors to ground, see [Figure 26](#). One capacitor reduces the noise caused by the 900 MHz carrier and the other reduces the noise caused by 1800/1900 MHz.

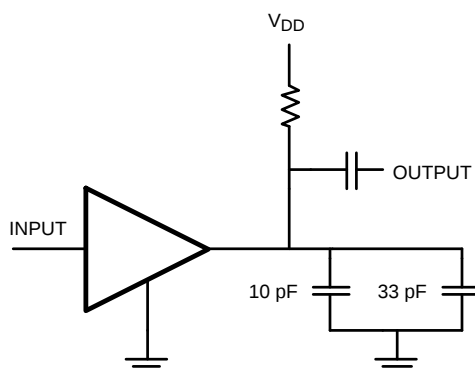


Figure 26. RF Noise Reduction

REVISION HISTORY

Changes from Revision G (May 2013) to Revision H

Page

- Changed layout of National Data Sheet to TI format [13](#)

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LMV1012TP-25/NOPB	ACTIVE	DSBGA	YPB	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012TPX-15/NOPB	ACTIVE	DSBGA	YPB	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		Samples
LMV1012TPX-25/NOPB	ACTIVE	DSBGA	YPB	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		Samples
LMV1012UP-07/NOPB	ACTIVE	DSBGA	YPC	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012UP-15/NOPB	ACTIVE	DSBGA	YPC	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012UP-20/NOPB	ACTIVE	DSBGA	YPC	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012UP-25/NOPB	ACTIVE	DSBGA	YPC	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV1012TP-25/NOPB	DSBGA	YPB	4	250	178.0	8.4	1.02	1.09	0.66	4.0	8.0	Q1
LMV1012TPX-15/NOPB	DSBGA	YPB	4	3000	178.0	8.4	1.02	1.09	0.66	4.0	8.0	Q1
LMV1012TPX-25/NOPB	DSBGA	YPB	4	3000	178.0	8.4	1.02	1.09	0.66	4.0	8.0	Q1
LMV1012UP-07/NOPB	DSBGA	YPC	4	250	178.0	8.4	1.02	1.09	0.56	4.0	8.0	Q1
LMV1012UP-15/NOPB	DSBGA	YPC	4	250	178.0	8.4	1.02	1.09	0.56	4.0	8.0	Q1
LMV1012UP-20/NOPB	DSBGA	YPC	4	250	178.0	8.4	1.02	1.09	0.56	4.0	8.0	Q1
LMV1012UP-25/NOPB	DSBGA	YPC	4	250	178.0	8.4	1.02	1.09	0.56	4.0	8.0	Q1

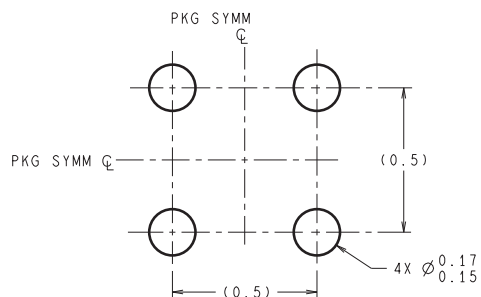
TAPE AND REEL BOX DIMENSIONS



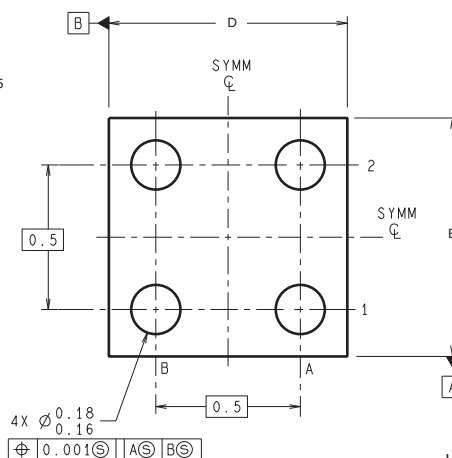
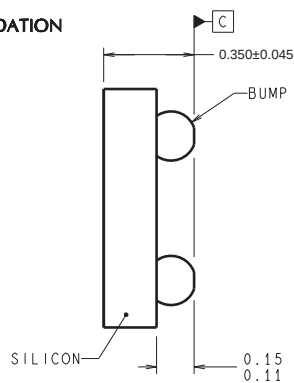
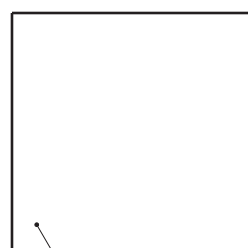
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV1012TP-25/NOPB	DSBGA	YPB	4	250	210.0	185.0	35.0
LMV1012TPX-15/NOPB	DSBGA	YPB	4	3000	210.0	185.0	35.0
LMV1012TPX-25/NOPB	DSBGA	YPB	4	3000	210.0	185.0	35.0
LMV1012UP-07/NOPB	DSBGA	YPC	4	250	210.0	185.0	35.0
LMV1012UP-15/NOPB	DSBGA	YPC	4	250	210.0	185.0	35.0
LMV1012UP-20/NOPB	DSBGA	YPC	4	250	210.0	185.0	35.0
LMV1012UP-25/NOPB	DSBGA	YPC	4	250	210.0	185.0	35.0

YPC0004



DIMENSIONS ARE IN MILLIMETERS
 DIMENSIONS IN () FOR REFERENCE ONLY

LAND PATTERN RECOMMENDATION

UPA04XXX (Rev C)

D: Max = 1.057 mm, Min = 0.996 mm

E: Max = 0.981 mm, Min = 0.92 mm

4215139/A 12/12

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 B. This drawing is subject to change without notice.

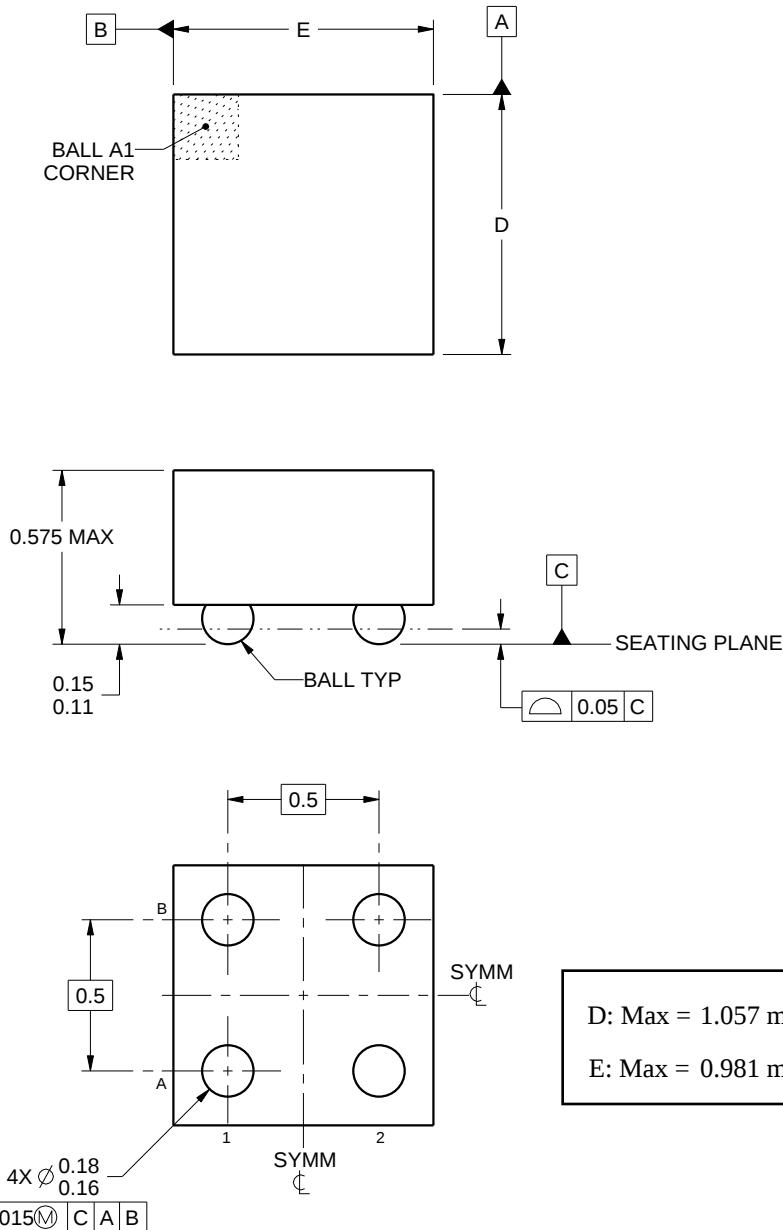


YPB0004

PACKAGE OUTLINE

DSBGA - 0.575 mm max height

DIE SIZE BALL GRID ARRAY



4215097/B 07/2016

NOTES:

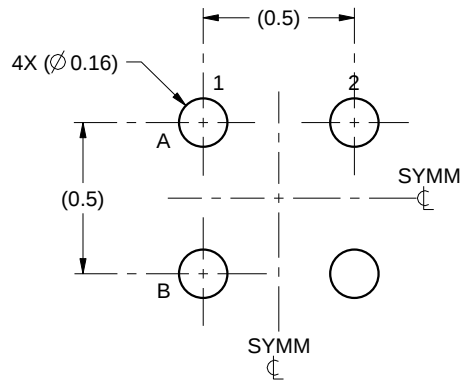
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

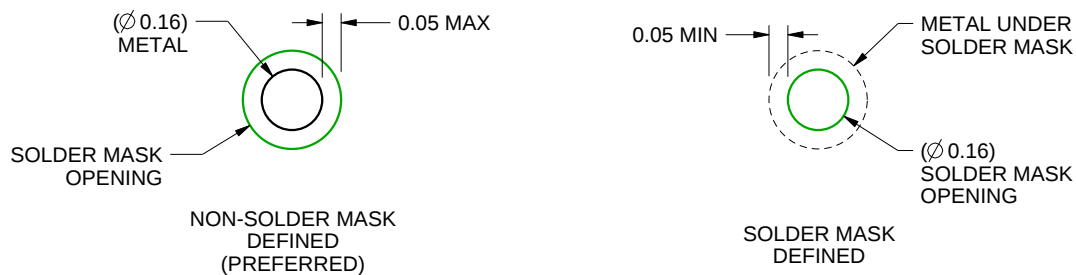
YPB0004

DSBGA - 0.575 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE
SCALE:40X



SOLDER MASK DETAILS
NOT TO SCALE

4215097/B 07/2016

NOTES: (continued)

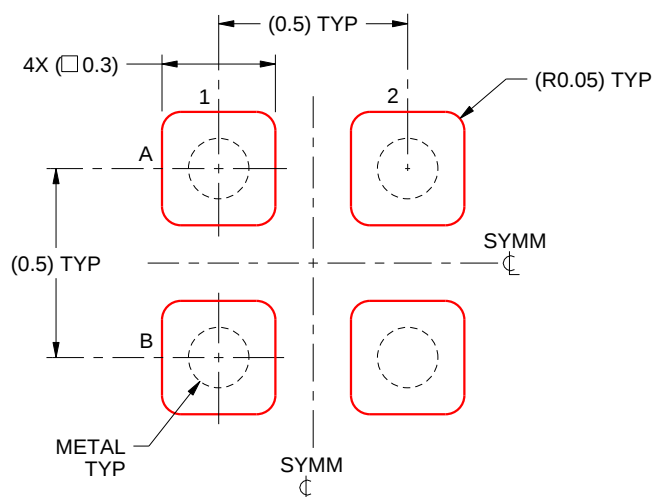
3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
See Texas Instruments Literature No. SNVA009 (www.ti.com/lit/snva009).

EXAMPLE STENCIL DESIGN

YPB00004

DSBGA - 0.575 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.125mm THICK STENCIL
SCALE:50X

4215097/B 07/2016

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2020, Texas Instruments Incorporated